









	<p><b>IPD50R650CE</b></p>
	<p><b>Hersteller-Teilenummer:</b> IPD50R650CE</p> <p><b>Hersteller / Marke:</b> International Rectifier (Infineon Technologies)</p> <p><b>Teil der Beschreibung:</b> IPD50R650CE Infineon Technologies</p> <p><b>Datenblätter:</b>  <a href="#">IPD50R650CE.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 2000 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IPD50R650CE
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	IPD50R650CE Infineon Technologies
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2000 pcs Stock
Serie	CoolMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	47W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.1A (Tc)
Rds On (Max) @ Id, Vgs	650 mOhm @ 1.8A, 13V
VGS (th) (Max) @ Id	3.5V @ 150µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	342pF @ 100V
Verpackung	Tape & Reel (TR)






















IPD50R650CE ist neu im Original, Suche IPD50R650CE Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD50R650CE International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD50R650CE: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>IPD50R520CPATMA1</b> International Rectifier (Infineon Technologies) LOW POWER_LEGACY</p>	 <p><b>IPD50R520CPBTMA1</b> International Rectifier (Infineon Technologies) LOW POWER_LEGACY</p>	 <p><b>IPD50R650CEAUMA1</b> International Rectifier (Infineon Technologies) CONSUMER</p>	 <p><b>IPD50R500CEAUMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 550V 7.6A TO252</p>
 <p><b>IPD50R500CEBTMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 500V 7.6A PG-TO252</p>	 <p><b>IPD50R650CEBTMA1</b> International Rectifier (Infineon Technologies) MOSFET N CH 500V 6.1A PG-TO252</p>	 <p><b>IPD50R650CEATMA1</b> International Rectifier (Infineon Technologies) MOSFET N CH 500V 6.1A PG-TO252</p>	 <p><b>IPD50R800CE</b> International Rectifier (Infineon Technologies) MOSFET N CH 500V 5A TO252</p>

heiße Teile

Mehr

 IPD50N04S4-08	 IPD50N04S4-10	 IPD50N04S4L-08	 IPD50N06L13	 IPD50N06S2-14
 IPD50N06S2L-13	 IPD50N06S3-09	 IPD50N06S3-15	 IPD50N06S3L-06	 IPD50N06S3L-08
 IPD50N06S3L-13	 IPD50N06S4-09	 IPD50N06S4-12	 IPD50N06S4L-08	 IPD50N06S4L-12
 IPD50N10S3L-16	 IPD50P03P4L-04	 IPD50P03P4L-11	 IPD50P04P4-13	 IPD50P04P4L-11
 IPD50R280CE	 IPD50R380CE	 IPD50R399CP	 IPD50R500CE	 IPD50R520CP
 IPD50R950CE	 IPD530N15N3	 IPD530N15N3G	 IPD530N15NG	 IPD600N25N3G
 IPD60N10S4L-12	 IPD60R1K0CE	 IPD60R1K4C6	 IPD60R1K5CE	 IPD60R2K0C6
 IPD60R360P	 IPD60R380C6	 IPD60R380E6	 IPD60R380P6	 IPD60R385CP
 IPD60R3K3C6	 IPD60R400CE	 IPD60R450E6	 IPD60R520C6	 IPD60R520CP
 IPD60R600C6	 IPD60R600CP	 IPD60R600E6	 IPD60R600P6	 IPD60R750E6

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